

SANYO Semiconductors DATA SHEET

An ON Semiconductor Company

SCH2202 — NPN Epitaxial Planar Silicon Transistor Switching, Driver Applications

Applications

· Low-frequency power amplifier, high-speed switch, motor drivers, muting

Features

- · Composite type with 2 NPN transistor contained in a single package, facilitating high-density mounting
- · Ultrasmall package permitting applied sets to be small and slim
- · Small ON-resistance (Ron)

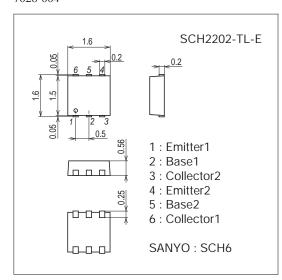
Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	VCBO		20	V
Collector-to-Emitter Voltage	VCEO		15	V
Emitter-to-Base Voltage	VEBO		5	V
Collector Current	IC		600	mA
Collector Current (Pulse)	ICP		1.2	А
Collector Dissipation	PC	Mounted on a ceramic board (600mm ² ×0.8mm)	0.4	W
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Package Dimensions

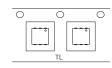
unit : mm (typ) 7028-004



Product & Package Information

Package : SCH6
JEITA, JEDEC : SOT-563
Minimum Packing Quantity : 5,000 pcs./reel

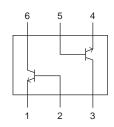
Packing Type : TL



Marking



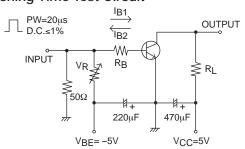
Electrical Connection



Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Linit
		Conditions	min	typ	max	Unit
Collector Cutoff Current	ICBO	V _{CB} =15V, I _E =0A			100	nA
Emitter Cutoff Current	I _{EBO}	V _{EB} =4V, I _C =0A			100	nA
DC Current Gain	hFE	V _{CE} =2V, I _C =10mA	300		800	
Gain-Bandwidth Product	fT	V _{CE} =2V, I _C =50mA		330		MHz
Output Capacitance	Cob	V _{CB} =10V, f=1MHz		3.2		pF
Collector-to-Emitter Saturation Voltage	V _{CE} (sat)	I _C =200mA, I _B =10mA		150	300	mV
Base-to-Emitter Saturation Voltage	V _{BE} (sat)	I _C =200mA, I _B =10mA		0.9	1.2	V
Collector-to-Base Breakdown Voltage	V(BR)CBO	I _C =10μA, I _E =0A	20			V
Collector-to-Emitter Breakdown Voltage	V(BR)CEO	IC=1mA, RBE=∞	15			V
Emitter-to-Base Breakdown Voltage	V(BR)EBO	I _E =10μA, I _C =0A	10			V
Turn-On Time	ton			30		ns
Storage Time t _{Si}	t _{Stg}	See specified Test Circuit.		77		ns
Fall Time	tf			40		ns

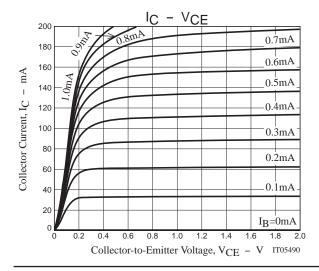
Switching Time Test Circuit

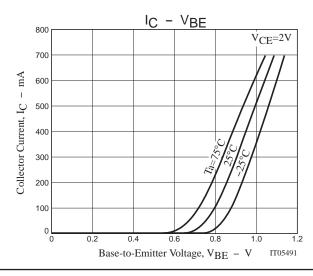


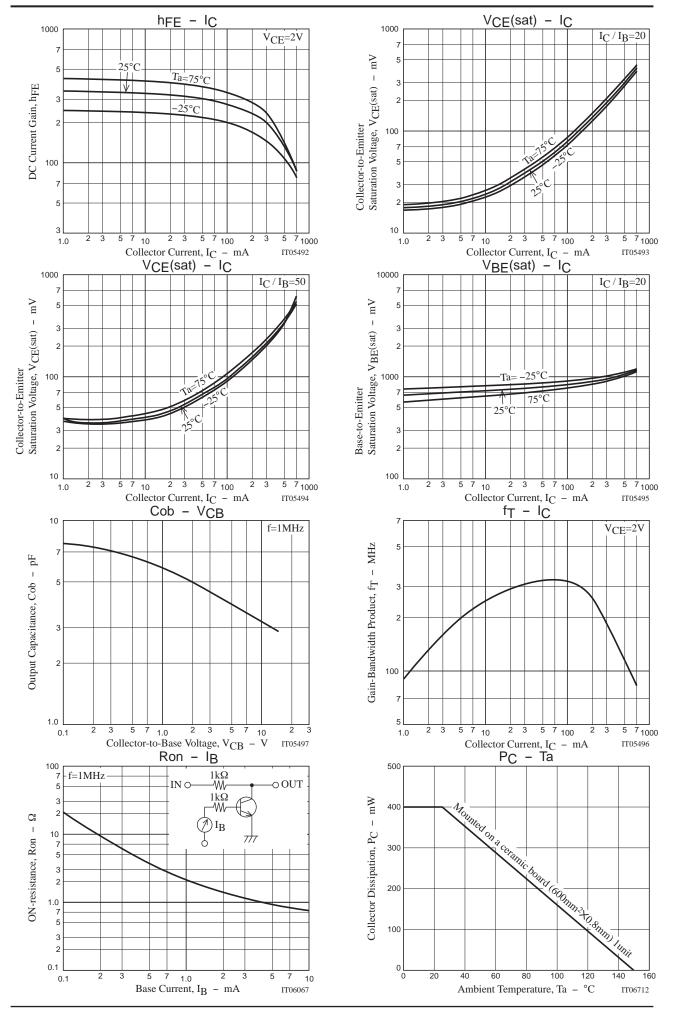
 $I_{C}=20I_{B1}=-20I_{B2}=400mA$

Ordering Information

Device	Package	Shipping	memo		
SCH2202-TL-E	SCH6	5,000pcs./reel	Pb Free and Halogen Free		





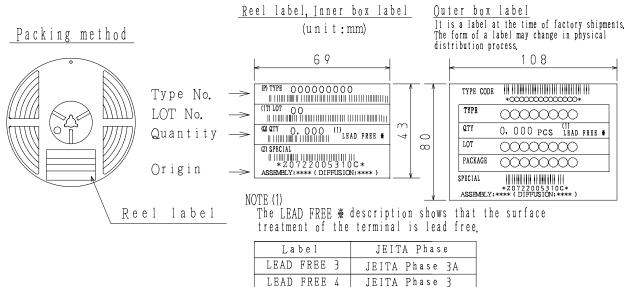


Taping Specification

SCH2202-TL-E

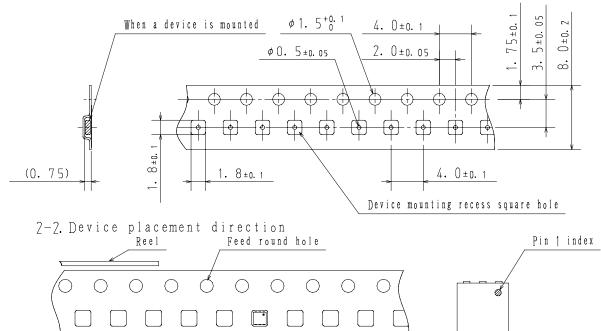
1. Packing Format

Package Name	Carrier Tape	Maximum Number of devices contained (pcs)			Packing format		
	Туре	Reel	Inner box	Outer box	Inner BOX (C-1)	Outer BOX (A-7)	
SCH6	SCH6	5,000	25, 000	150,000	5 reels contained	6 inner boxes contained	
					Dimensions:mm (external)	Dimensions:mm (external)	
					183×72×185	440×195×210	



2. Taping configuration

2-1. Carrier tape size (unit:mm)



Those with pin 1 index on the feed hole side · · · · · TL

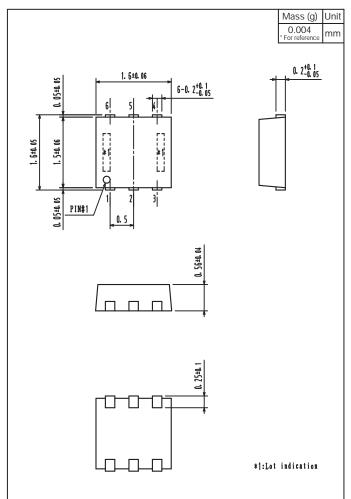
ΤL

→ Feed direction

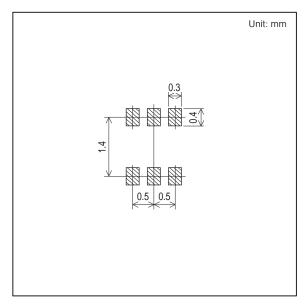
Carrier tape

Outline Drawing

SCH2202-TL-E



Land Pattern Example



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